

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

IRFSL7762

D(2)

• FEATURES

- With To-262 package
- · Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

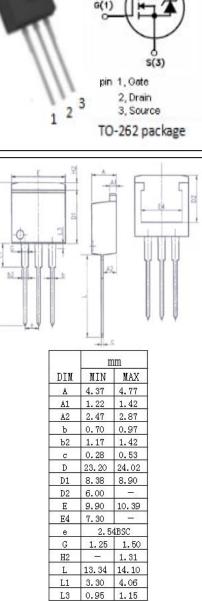
Switching applications

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)					
SYMBOL	PARAMETER	VALUE	UNIT		
V _{DSS}	Drain-Source Voltage	75	V		
V _{GSS}	Gate-Source Voltage	±20	V		
ID	Drain Current-ContinuousTc=25℃ Tc=100℃	85 60	A		
I _{DM}	Drain Current-Single Pulsed	335	А		
PD	Total Dissipation @T _c =25°C	140	W		
T _{ch}	Max. Operating Junction Temperature	175	°C		
T _{stg}	Storage Temperature	-55~175	°C		

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	1.05	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	

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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	75			v
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.1mA	2.1		3.7	v
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =51A		5.6	6.7	mΩ
lgss	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =75V; V _{GS} = 0V;Tj=25℃ V _{DS} =75V; V _{GS} = 0V;Tj=125℃			1 150	μA
VSDF	Diode forward voltage	I_{SD} =51A, V_{GS} = 0 Vs		1.0	1.2	V



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